

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

# TLP3061(S),TLP3062(S),TLP3063(S)

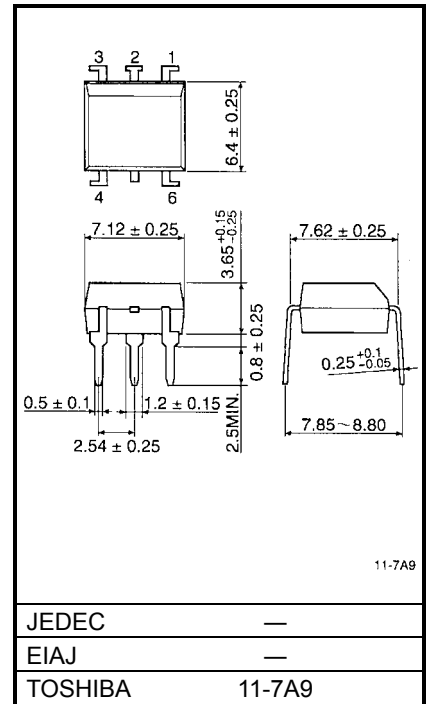
Unit: mm

OFFICE MACHINE  
HOUSEHOLD USE EQUIPMENT  
TRIAC DRIVER  
SOLID STATE RELAY

The TOSHIBA TLP3061 (S), TLP3062 (S), TLP3063 (S) consist of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

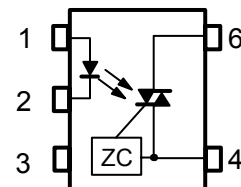
- Peak Off-State Voltage : 600 V (min)
- Trigger LED Current : 15 mA (max) (TLP3061(S))  
10 mA (max) (TLP3062(S))  
5 mA (max) (TLP3063(S))
- On-State Current : 100 mA (max)
- Isolation Voltage : 5000 Vrms (min)
- UL Recognized : UL1577, File No. E67349
- SEMKO Approved : SS EN60065  
SS EN60950, File No.9841113
- BSI Approved : BS EN60065, File No.8385  
BS EN60950, File No.8386
- Option (D4) type  
VDE approved: DIN EN60747-5-2  
Approved No. 40009302  
Maximum operating insulation voltage: 890V<sub>PK</sub>  
Highest permissible over voltage: 8000V<sub>PK</sub>  
(Note):When a EN60747-5-2 approved type is needed,  
please designate the "Option (D4)"

	Construction mechanical rating	
	7.62 mm pich Standard Type	10.16 mm pich TLPxxxxF type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)



weight: 0.39g

### Pin Configuration (top view)



- 1: Anode
- 2: Cathode
- 3: N.C.
- 4: Terminal 1
- 6: Terminal 2

ZC:Zero-cross Circuit

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	$I_F$	50	mA
	Forward current derating (Ta ≥ 53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C
	Peak forward current (100 μs pulse, 100 pps)	$I_{FP}$	1	A
	Power dissipation	$P_D$	100	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_D / ^\circ\text{C}$	-1.0	mW / °C
	Reverse voltage	$V_R$	5	V
	Junction temperature	$T_j$	125	°C
Detector	Off-state output terminal voltage	$V_{DRM}$	600	V
	On-state RMS current	Ta = 25°C	100	mA
		Ta = 70°C	50	
	On-state current derating (Ta ≥ 25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C
	Peak on-state current (100 μs pulse, 120 pps)	$I_{TP}$	2	A
	Peak nonrepetitive surge current (Pw = 10 ms, DC = 10%)	$I_{TSM}$	1.2	A
	Power dissipation	$P_D$	300	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_D / ^\circ\text{C}$	-4.0	mW / °C
Junction temperature	$T_j$	115	°C	
Storage temperature range	$T_{stg}$	-55~150	°C	
Operating temperature range	$T_{opr}$	-40~100	°C	
Lead soldering temperature (10 s)	$T_{sol}$	260	°C	
Total package power dissipation	$P_T$	330	mW	
Total package power dissipation derating (Ta ≥ 25°C)	$\Delta P_T / ^\circ\text{C}$	-4.4	mW / °C	
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)	$BV_S$	5000	Vrms	

(Note 1) Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4 and 6 shorted together.

## Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	$V_{AC}$	—	—	240	Vac
Forward current	$I_F^*$	15	20	25	mA
Peak on-state current	$I_{TP}$	—	—	1	A
Operating temperature	$T_{opr}$	-25	—	85	°C

※ In the case of TLP3062

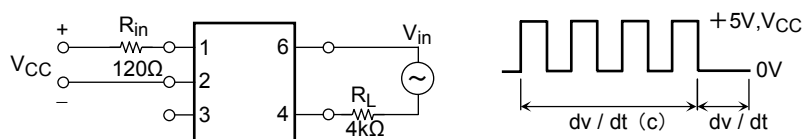
## Individual Electrical Characteristics (Ta = 25°C)

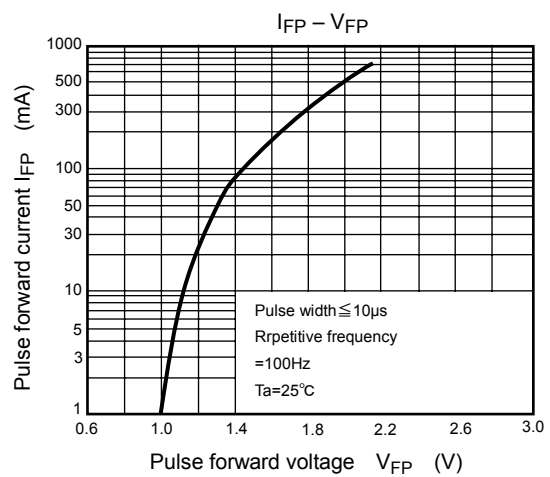
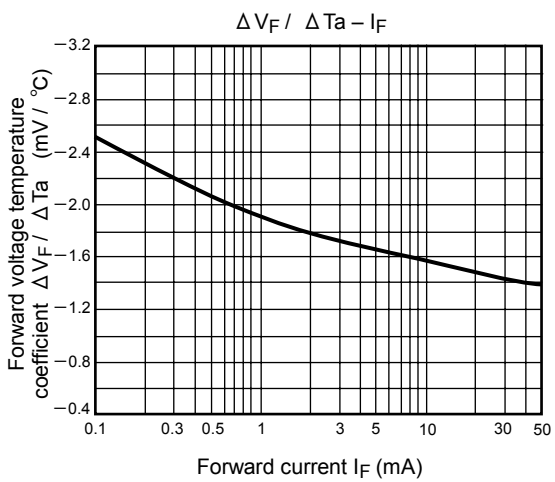
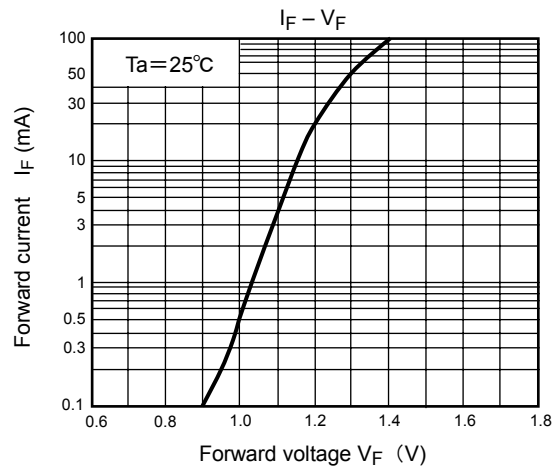
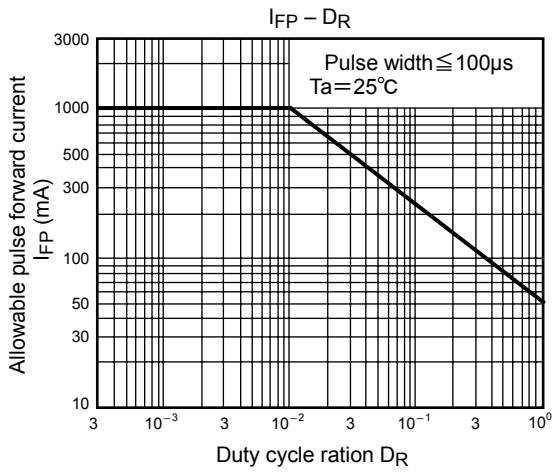
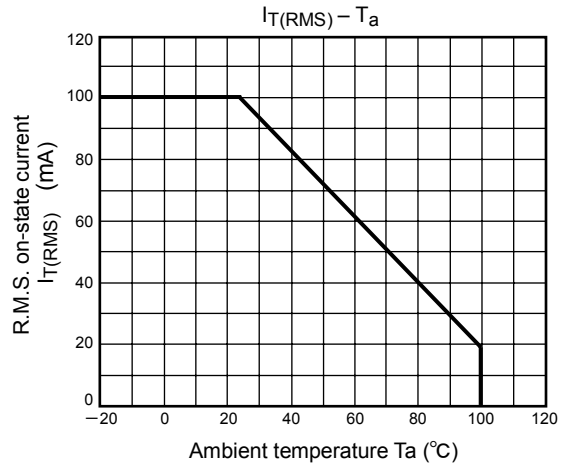
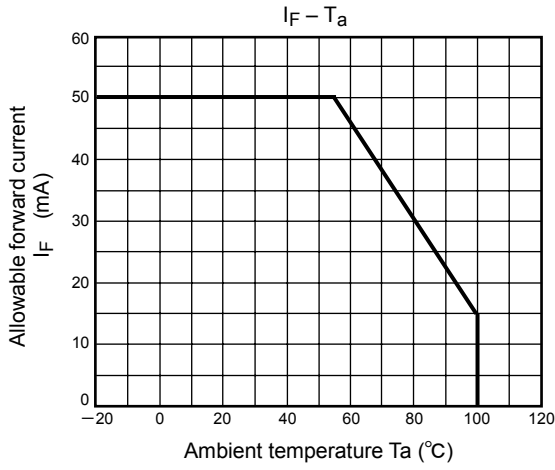
Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF
Detector	Peak off-state current	$I_{DRM}$	$V_{DRM} = 600 \text{ V}$	—	10	1000	nA
	Peak on-state voltage	$V_{TM}$	$I_{TM} = 100 \text{ mA}$	—	1.7	3.0	V
	Holding current	$I_H$	—	—	0.6	—	mA
	Critical rate of rise of off-state voltage	$dv/dt$	$V_{in} = 240 \text{ Vrms}, T_a = 85^\circ\text{C}$ (Fig.1)	200	500	—	V / $\mu\text{s}$
	Critical rate of rise of commutating voltage	$dv/dt(c)$	$V_{in} = 60 \text{ Vrms}, I_T = 15\text{mA}$ (Fig.1)	—	0.2	—	V / $\mu\text{s}$

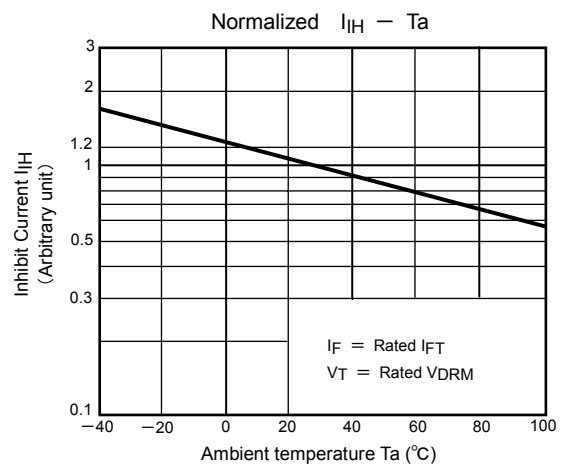
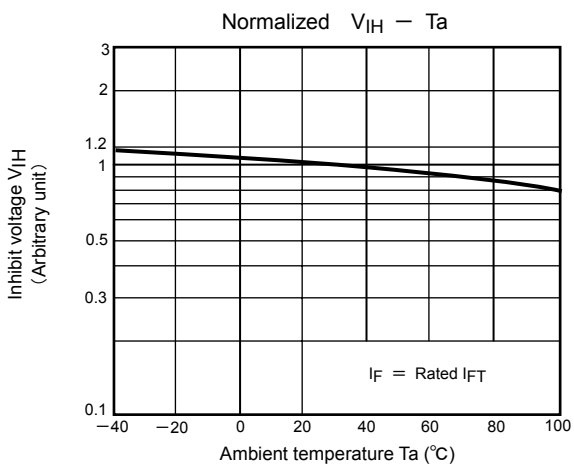
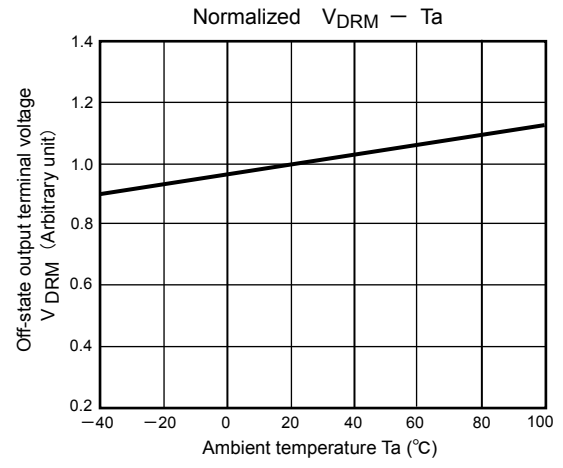
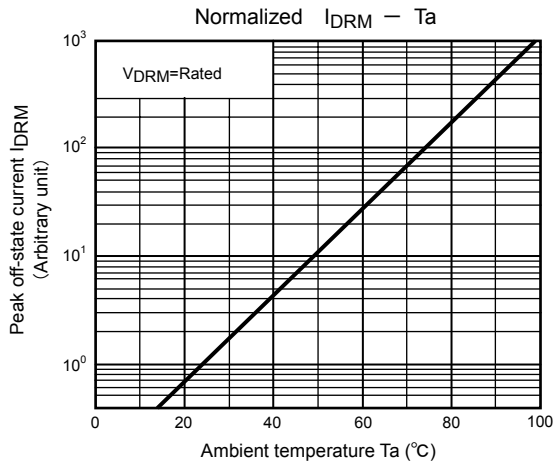
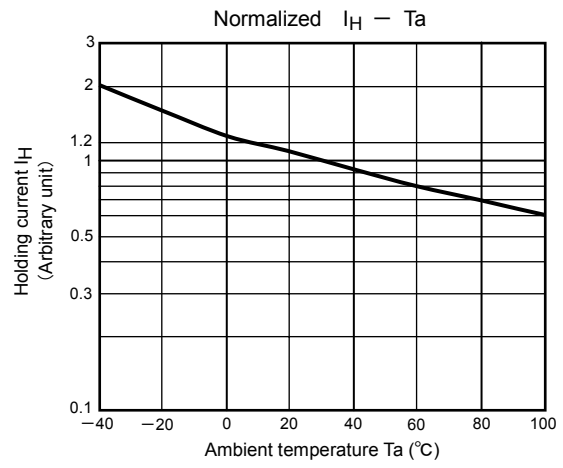
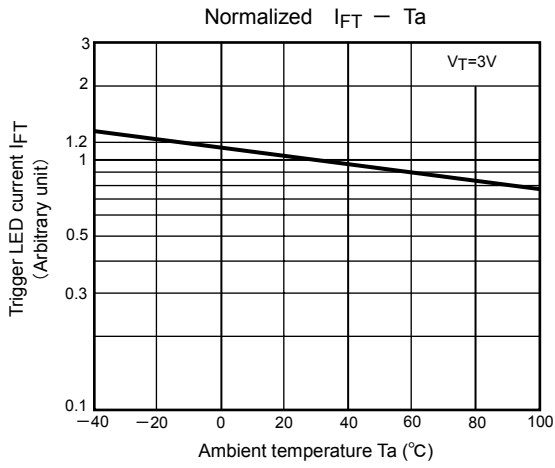
## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	TLP3061(S)	$I_{FT}$	$V_T = 6 \text{ V}$	—	—	15	mA
	TLP3062(S)			—	5	10	
	TLP3063(S)			—	—	5	
Inhibit voltage	$V_{IH}$	$I_F = \text{rated } I_{FT}$	—	—	50	V	
Leakage in inhibited state	$I_{IH}$	$I_F = \text{rated } I_{FT}$ $V_T = \text{rated } V_{DRM}$	—	100	300	$\mu\text{A}$	
Capacitance input to output	$C_S$	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF	
Isolation resistance	$R_S$	$V_S = 500 \text{ V (R.H.} \leq 60\%)$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$	
Isolation voltage	$BV_S$	AC, 1 minute	5000	—	—	Vrms	
		AC, 1 second, in oil	—	10000	—		
		DC, 1 minute, in oil	—	10000	—	V <sub>dc</sub>	

Fig. 1  $dv/dt$  test circuit







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